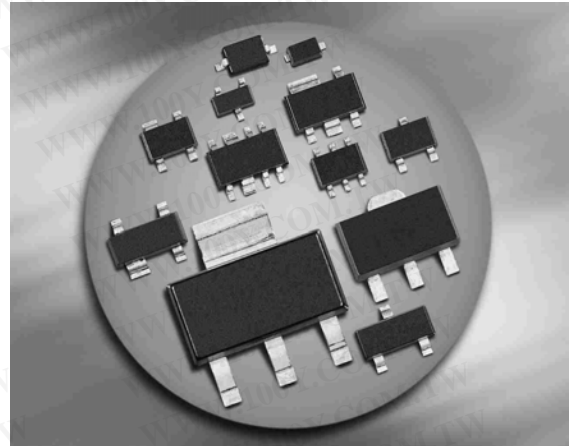
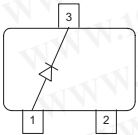


Silicon Schottky Diode

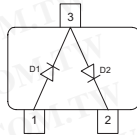
- For mixer applications in VHF/UHF range
- For high-speed switching application



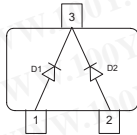
BAT17



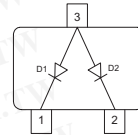
**BAT17-04
BAT17-04W**



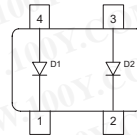
**BAT17-05
BAT17-05W**



**BAT17-06
BAT17-06W**



BAT17-07



ESD: Electrostatic discharge sensitive device, observe handling precaution!

Type	Package	Configuration	L_S (nH)	Marking
BAT17	SOT23	single	1.8	53s
BAT17-04	SOT23	series	1.8	54s
BAT17-04W	SOT323	series	1.4	54s
BAT17-05	SOT23	common cathode	1.8	55s
BAT17-05W	SOT323	common cathode	1.4	55s
BAT17-06	SOT23	common anode	1.8	56s
BAT17-06W	SOT323	common anode	1.4	56s
BAT17-07	SOT143	parallel pair	2	57s

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	4	V
Forward current	I_F	130	mA
Total power dissipation	P_{tot}		mW
BAT17, $T_S \leq 77^\circ\text{C}$		150	
BAT17-04, BAT17-06, $T_S \leq 61^\circ\text{C}$		150	
BAT17-05, $T_S \leq 46^\circ\text{C}$		150	
BAT17-04W, -05W, -6W, $T_S \leq 92^\circ\text{C}$		150	
BAT17-07, $T_S \leq 60^\circ\text{C}$		150	
Junction temperature	T_j	150	$^\circ\text{C}$
Operating temperature range	T_{op}	-55 ... 125	
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BAT17		≤ 490	
BAT17-04, BAT17-06, BAT17-07		≤ 590	
BAT17-05		≤ 690	
BAT17-04W, BAT17-05W, BAT17-06W		≤ 390	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)} = 10 \mu\text{A}$	$V_{(BR)}$	4	-	-	V
Reverse current $V_R = 3 \text{ V}$ $V_R = 4 \text{ V}$ $V_R = 3 \text{ V}, T_A = 60^\circ\text{C}$	I_R	-	-	0.25 10 1.25	μA
Forward voltage $I_F = 0.1 \text{ mA}$ $I_F = 1 \text{ mA}$ $I_F = 10 \text{ mA}$	V_F	200 250 350	275 340 425	350 450 600	mV
Forward voltage matching ¹⁾ $I_F = 1 \text{ mA}$	ΔV_F	-	-	20	

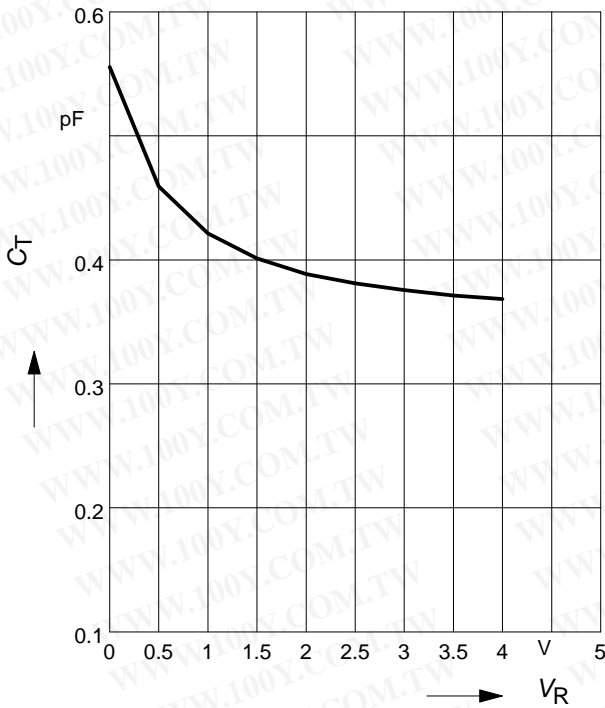
AC Characteristics

Diode capacitance $V_R = 0, f = 1 \text{ MHz}$	C_T	0.4	0.55	0.75	pF
Differential forward resistance $I_F = 5 \text{ mA}, f = 10 \text{ kHz}$	R_F	-	8	15	Ω

¹⁾ ΔV_F is the difference between lowest and highest V_F in multiple diode component.

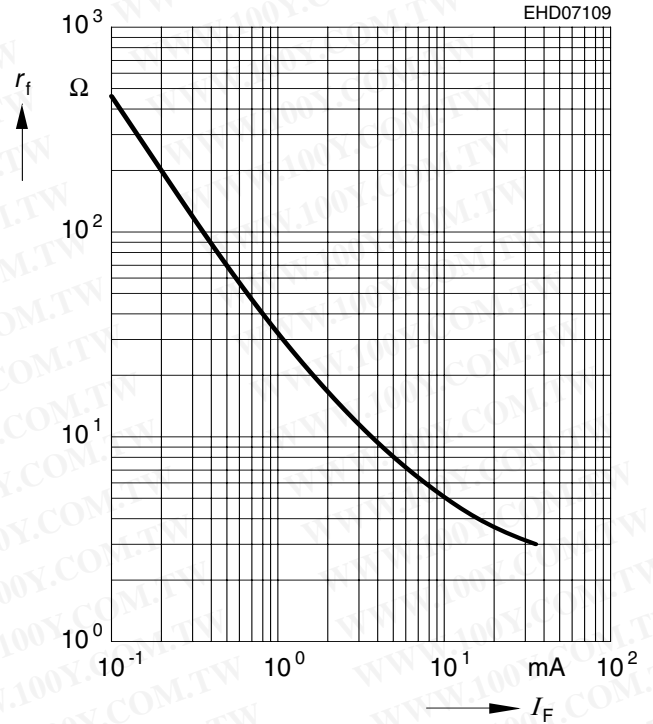
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



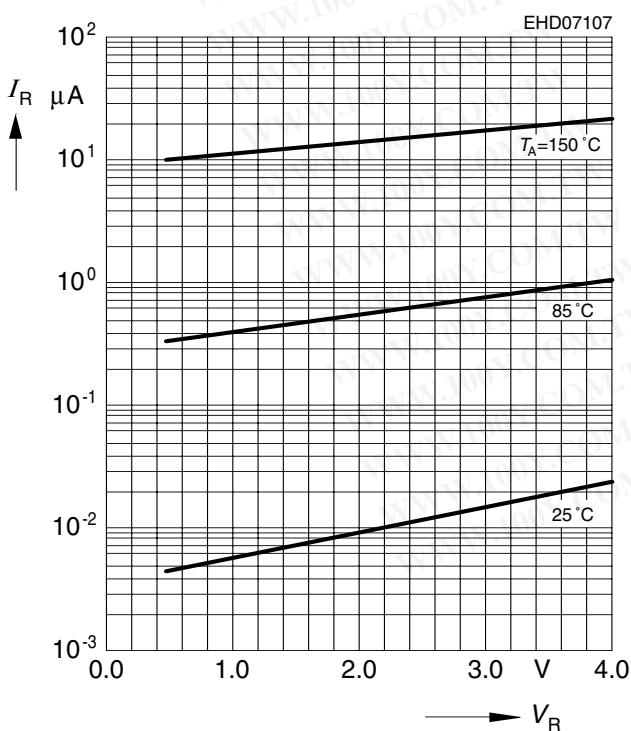
Forward resistance $r_f = f(I_F)$

$f = 10\text{kHz}$



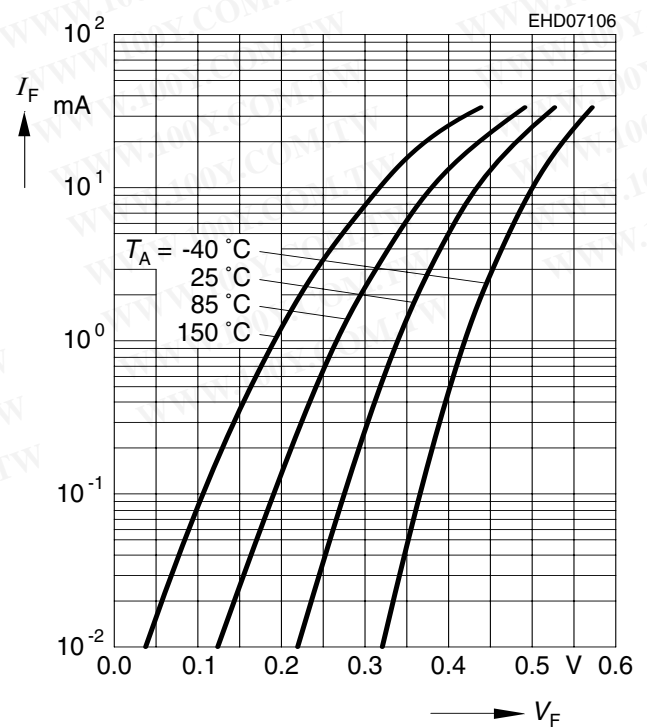
Reverse current $I_R = f(V_R)$

$T_A = \text{Parameter}$



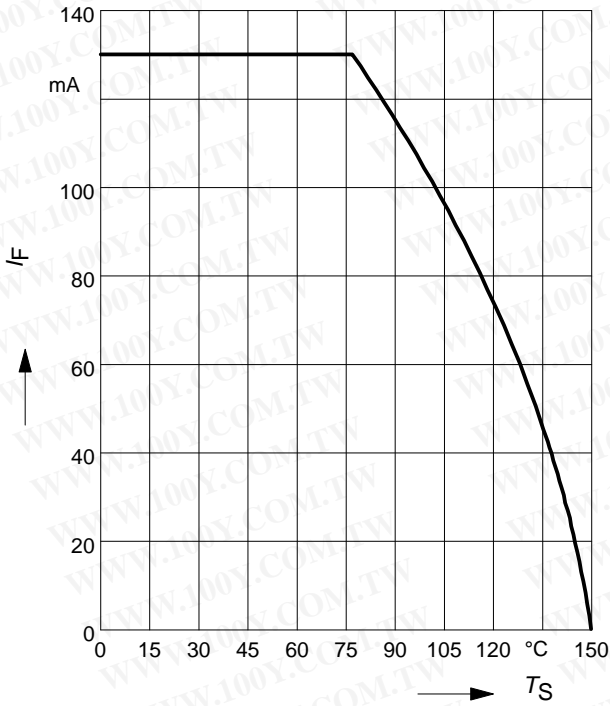
Forward current $I_F = f(V_F)$

$T_A = \text{Parameter}$



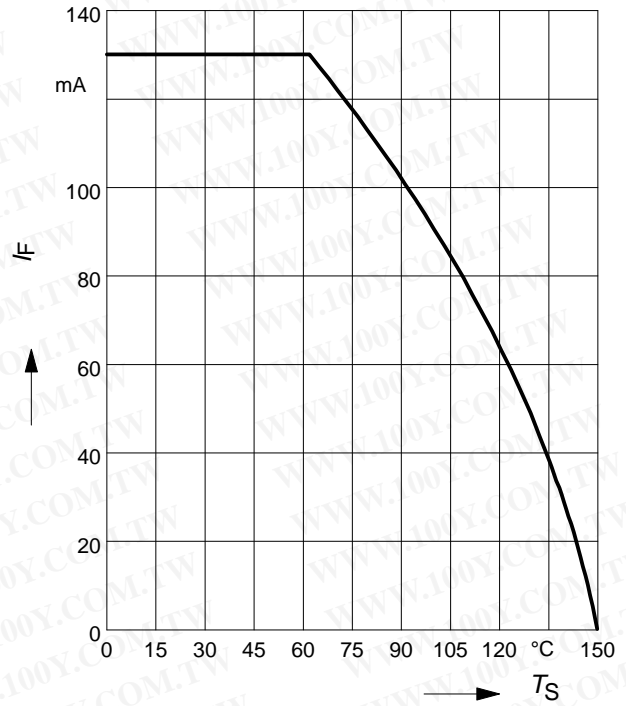
Forward current $I_F = f(T_S)$

BAT17



Forward current $I_F = f(T_S)$

BAT17-04, BAT17-06, BAT17-07



Forward current $I_F = f(T_S)$

BAT17-05

